
	<h2>SI2347DS-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI2347DS-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 30V 5A SOT-23</p> <p>Datenblätter:  SI2347DS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 90908 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2347DS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 30V 5A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	90908 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3
Verlustleistung (max)	1.2W (Ta), 1.7W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5A (Tc)
Rds On (Max) @ Id, Vgs	42 mOhm @ 3.8A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	705pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)




















SI2347DS-T1-GE3 ist neu im Original, Suche SI2347DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2347DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2347DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI2347DS-T1-E3 VISHAY SI2347DS-T1-E3 VISHAY	 SI2351DS Vishay Precision Group SI2351DS VISHAY	 SI2343DS-T1-GE3 Vishay / Siliconix MOSFET P-CH 30V 3.1A SOT-23	 SI2344DS-E3 VISHAY SI2344DS-E3 VISHAY
 SI2343DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 3.1A SOT-23	 SI2351DS-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 2.8A SOT23-3	 SI2351DS-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2.8A SOT23-3	 SI2350DS VISHAY SI2350DS VISHAY

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Mehr

 SI2337DS-T1-E3	 SI2337DS-T1-GE3	 SI2337DS-T1-GE3	 SI2338DS-T1-E3	 SI2338DS-T1-GE3
 SI2338DS-T1-GE3	 SI2341DS	 SI2341DS-T1-E3	 SI2341DS-T1-E3	 SI2341DS-T1-GE3
 SI2341DS-T1-GE3	 SI2342DS-T1-E3	 SI2342DS-T1-GE3	 SI2342DS-T1-GE3	 SI2343ADS-T1-GE3
 SI2343CDS	 SI2343CDS-T1-E3	 SI2343CDS-T1-GE3	 SI2343CDS-T1-GE3	 SI2343DS-T1-E3
 SI2343DS-T1-E3	 SI2343DS-T1-GE3	 SI2343DS-T1-GE3	 SI2344DS-E3	 SI2347DS-T1-GE3
 SI2351DS-T1-E3	 SI2351DS-T1-E3	 SI2351DS-T1-GE3	 SI2351DS-T1-GE3	 SI2356DS-T1-GE3
 SI2356DS-T1-GE3	 SI2365EDS	 SI2365EDS-T1-GE3	 SI2365EDS-T1-GE3	 SI2366DS-T1-E3
 SI2366DS-T1-GE	 SI2366DS-T1-GE3	 SI2366DS-T1-GE3	 SI2367DS-T1-E3	 SI2367DS-T1-GE3
 SI2367DS-T1-GE3	 SI2369DS-T1-GE3	 SI2369DS-T1-GE3	 SI2371EDS-T1-GE3	 SI2371EDS-T1-GE3
 SI2372DS-T1-E3	 SI2372DS-T1-GE3	 SI2372DS-T1-GE3	 SI2374DS-T1-GE3	 SI2374DS-T1-GE3

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